

Features

- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant(Note 1) ("P" Suffix Designates Compliant. See Ordering Information)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Low Switching Losses and High Efficiency
- High Forward Surge Current Caability
- Low Reverse Leakage
- Planar Structure Die and Soft Recovery Characteristics

60 Amp Ultrafast Recovery Rectifier 400 Volts

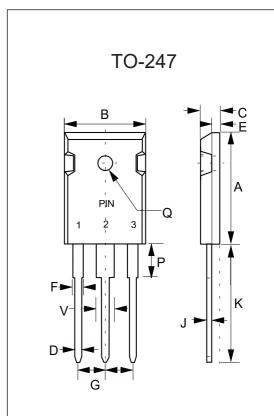
Maximum Ratings @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}		
Working Peak Reverse Voltage	V _{RWM}	400	V
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{RMS}	280	V
Average Rectified Forward Current			
Per Diode Per Device	I _{F(AV)}	30 60	А
Non-Repetitive Peak Surge Current @8.3ms Half Sine Wave(Per Diode)	I _{FSM}	300	А
Current Squared Time @ 1ms≤t≤8.3ms(Per Diode)	l²t	373	A ² s

Internal Structure

Pin	Description	Simplified Outline	Graphic Symbol
1&3	Anode		
2	Cathode	мсс.	PIN 1 ∘ →
		MUR6040PTS →+ →+ →+ →+ →+ →+ →+ →+ →+ →	PIN 3 PIN 2
		V V V	

Note :1. High temperature solder exemption applied, see EU directive annex 7a.



DIMENIOLONIO							
	DIMENSIONS						
DIM INCH		HES MN		IM	NOTE		
Dilvi	MIN MAX		MIN	MAX	NOTE		
Α	0.787	0.866	20.00	22.00			
В	0.598	0.638	15.20	16.20			
С	0.185	0.208	4.70	5.30			
D	0.035	0.059	0.90	1.50			
Е	0.059	0.094	1.50	2.40			
F	0.067	0.091	1.70	2.30			
J	0.019	0.031	0.48	0.80			
K	0.748	0.833	19.00	21.15			
Р	0.122	0.189	3.10	4.80			
Q	0.118	0.150	3.00	3.80	Ф		
V	0.106	0.134	2.70	3.40			
G	0.197	0.224	5.00	5.70			



Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
TJ	Operating Junction Temperature Range		-55		150	°C
T _{stg}	Storage Temperature Range		-55		150	°C
Rth _(J-C)	Thermal Resistance from Junction to Case	Per Diode		0.65		°C/W
Rth _(J-A)	Thermal Resistance from Junction to Ambient	Free in Air		40		°C/W

Electrical Characteristics @ 25°C Unless Otherwise Specified(Per Diode)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Forward Voltage	V _F	I _F =30A;T _J =25°C		1.20	1.40	V
		I _F =30A;T _J =125°C		1.04	1.20	V
Reverse Current	I _R	V _R =400V;T _J =25°C			5	
		V _R =400V;T _J =125°C			200	μA
Junction Capacitance	CJ	V _R =4V;f=1MHz;T _J =25°C		260		pF

Dynamic Recovery Characteristics @ 25°C Unless Otherwise Specified(Per Diode)

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
	t _{rr}	I _F =0.5A; I _R =1.0A;I _{RR} =0.25A;T _J =25°C			28	50	
Reverse Recovery Time		I _F =30A d _{iF} /d _t = -200A/μs V _{RM} =200V	T _J =25°C		45		ns
			T _J =125°C		77		
Peak Recovery Current	I _{RRM}		T _J =25°C		4		
			T _J =125°C		10		Α
Reverse Recovery Charge	Q _{rr}		T _J =25°C		92		nC
			T _J =125°C		395		IIC



Curve Characteristics

Fig. 1 - Forward Current Derating Curve

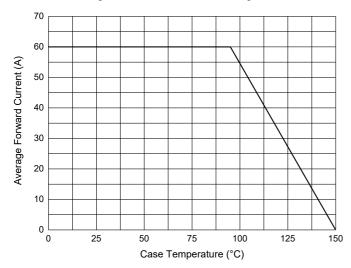


Fig. 3 - Typical Forward Characteristics

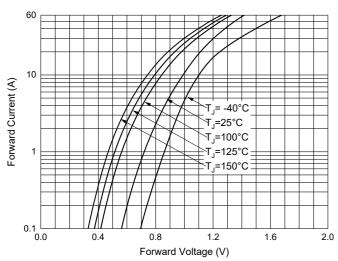


Fig. 5 - Typical Capacitance Characteristics

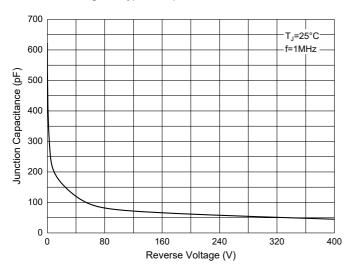


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

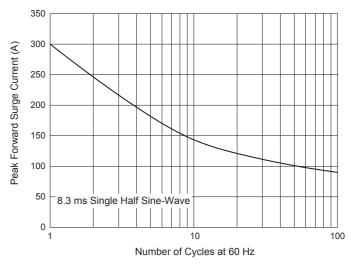


Fig. 4 - Typical Reverse Leakage Characteristics

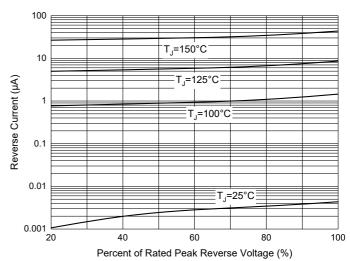
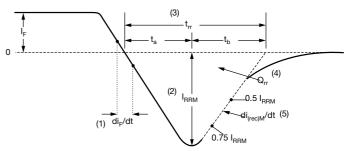


Fig. 6 - Reverse Recovery Waveform and Definitions



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RBM} and 0.50 I_{RBM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}



Ordering Information

Device	Packing
Part Number-BP	Bulk:30pcs/Tube,360pcs/Box,1.8Kpcs/Carton

Note: Adding "-HF" Suffix For Halogen Free, eg. Part Number-BP-HF

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